QUICKSWITCH[®] PRODUCTS 2.5V / 3.3V 24-BIT HIGH BANDWIDTH BUS SWITCH

DESCRIPTION:

digital buses.

1

IDTQS3VH16211

The QS3VH16211 HotSwitch is a 24-bit high bandwidth bus switch. The

QS3VH16211 has very low ON resistance, resulting in under 250ps

propagation delay through the switch. This device operates as a 24-bit bus

switch. When TOE is low, 1An is connected to 1Bn. When TOE is low, 2An

is connected to 2Bn. In the OFF and ON states, the switches are 5V-tolerant.

In the OFF state, the switches offer very high impedance at the terminals.

and over-voltage tolerance makes the QS3VH16211 ideal for high perfor-

mance communications applications. It is also suitable for switching wide

The QS3VH16211 is characterized for operation from -40°C to +85°C.

The combination of near-zero propagation delay, high OFF impedance,

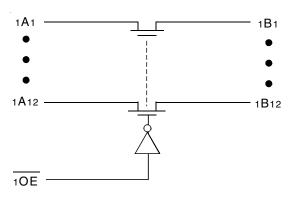
FEATURES:

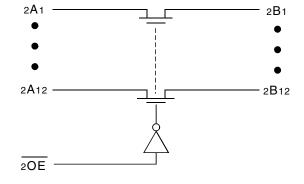
- · N channel FET switches with no parasitic diode to Vcc
 - Isolation under power-off conditions
 - No DC path to Vcc or GND
 - 5V tolerant in OFF and ON state
- 5V tolerant I/Os
- Low Ron 4Ω typical
- · Flat Ron characteristics over operating range
- · Rail-to-rail switching 0 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- · Excellent Ron matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth up to 500 MHz
- · LVTTL-compatible control Inputs
- · Undershoot Clamp Diodes on all switch and control Inputs
- Low I/O capacitance, 4pF typical
- · Available in TSSOP package

APPLICATIONS:

- · Hot-swapping
- 10/100 Base-T, Ethernet LAN switch
- · Low distortion analog switch
- Replaces mechanical relay
- ATM 25/155 switching

FUNCTIONAL BLOCK DIAGRAM



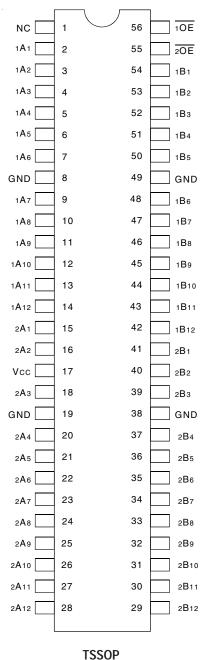


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INDUSTRIAL TEMPERATURE RANGE

OCTOBER 2008

PINCONFIGURATION



TOP VIEW

INDUSTRIAL TEMPERATURE RANGE

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max.	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	– 0.5 to 4.6	V
VTERM(3)	DC Switch Voltage Vs	– 0.5 to 5.5	V
VTERM ⁽³⁾	DC Input Voltage VIN	– 0.5 to 5.5	V
VAC	AC Input Voltage (pulse width ≤20ns)	- 3	V
Ιουτ	DC Output Current (max. current/pin)	120	mA
Tstg	Storage Temperature	-65 to +150	°C

NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

CAPACITANCE ($T_A = +25^{\circ}C$, f = 1MHz, $V_{IN} = 0V$, $V_{OUT} = 0V$)

Symbol	Parameter ⁽¹⁾	Тур.	Max.	Unit
Cin	Control Inputs	3	5	pF
Ci/o	Quickswitch Channels (Switch OFF)	4	6	pF
Ci/o	Quickswitch Channels (Switch ON)	8	12	pF
NOTE				

1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	I/O	Description
xA1 - xA12	I/O	Bus A
xB1 - xB12	I/O	Bus B
10E - 20E	I	Data Select

FUNCTION TABLE⁽¹⁾

1 0 E	20E	1 Ax	2 A X	Function
L	L	1Bx	2Bx	1Ax to 1Bx, 2Ax to 2Bx
L	Н	1Bx	Z	1Ax to 1Bx
Н	L	Z	2Bx	2Ax to 2Bx
Н	Н	Z	Z	Disconnect

NOTE:

1. H = HIGH Voltage Level L = LOW Voltage Level

Z = High-Impedence

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE⁽¹⁾

Following Conditions Apply Unless Otherwise Specified:

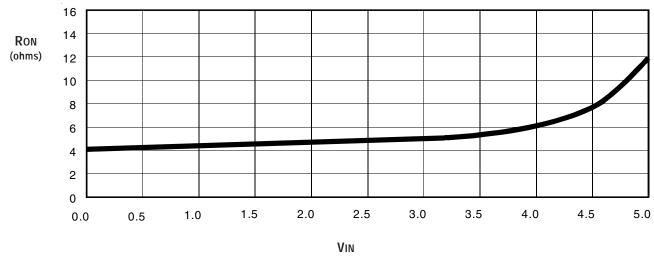
Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = $3.3V \pm 0.3V$

Symbol	Parameter	Test Conditions			Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HI	GH	Vcc = 2.3V to 2.7V	1.7	_	_	V
		for Control Inputs	Γ	Vcc = 2.7V to 3.6V	2	_	—	
Vil	Input LOW Voltage	Guaranteed Logic HI	GH	Vcc = 2.3V to 2.7V	_	—	0.7	V
		for Control Inputs	Γ	Vcc = 2.7V to 3.6V	—	—	0.8	
lin	Input Leakage Current (Control Inputs)	$0V \le VIN \le VCC$		_	—	±1	μA	
loz	Off-State Current (Hi-Z)	$0V \le VOUT \le 5V$, Switches OFF		_	—	±1	μA	
IOFF	Data Input/Output Power Off Leakage	VIN or VOUT 0V to 5V, VCC = 0V		—	—	±1	μA	
		VCC = 2.3V	VIN = 0V	ION = 30mA	_	6	8	
Ron	Switch ON Resistance	(Typ. at Vcc = 2.5V)	VIN = 1.7V	Ion = 15mA	—	7	9	Ω
		VCC = 3V	VIN = 0V	ION = 30mA	_	4	6	
			VIN = 2.4V	ION = 15mA	_	5	8	

NOTE:

1. Typical values are at Vcc = 3.3V and TA = 25°C, unless otherwise noted.

TYPICAL ON RESISTANCE vs VIN AT Vcc = 3.3V



(Volts)

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Min.	Тур.	Max.	Unit
lcco	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc, f = 0	-	1.5	3	mA
Δlcc	Power Supply Current ^(2,3) per Input HIGH	Vcc = Max., VIN = 3V, f = 0 per Control Input	_	—	30	μA
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = 3.3V, A and B Pins Open, Control Inputs	See Typical	ccd vs Enable	Frequency gra	ph below
		Toggling @ 50% Duty Cycle				

NOTES:

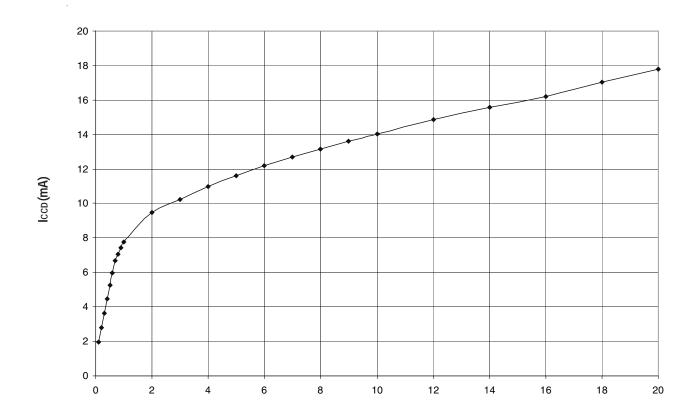
1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per input driven at the specified level. A and B pins do not contribute to Δ Icc.

3. This parameter is guaranteed but not tested.

4. This parameter represents the current required to switch internal capacitance at the specified frequency. The A and B inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

TYPICAL ICCD VS ENABLE FREQUENCY CURVE AT VCC = 3.3V



ENABLE FREQUENCY (MHz)

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$

		$Vcc = 2.5 \pm 0.2V^{(1)}$		$Vcc = 3.3 \pm 0.3 V^{(1)}$		
Symbol	Parameter	Min. ⁽⁴⁾	Max.	Min. ⁽⁴⁾	Max.	Unit
t PLH	Data Propagation Delay ^(2,3)		0.2	—	0.2	ns
t PHL	xAx to xBx or xBx to xAx					
tРZH	Switch Turn-On Delay	1.5	9	1.5	9	ns
tPZL	\overline{xOE} to xAx or xBx					
t PHZ	Switch Turn-Off Delay	1.5	8.5	1.5	8.5	ns
tPLZ	\overline{xOE} to xAx or xBx					
fxOE	Operating Frequency - Enable ^(2,5)		7.5	—	20	MHz

NOTES:

1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.

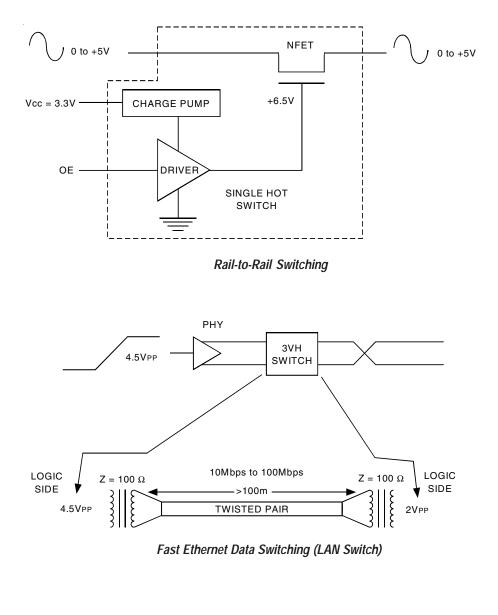
2. This parameter is guaranteed but not production tested.

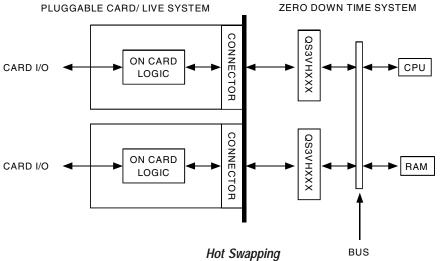
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.2ns at CL = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

4. Minimums are guaranteed but not production tested.

5. Maximum toggle frequency for \overline{xOE} control input (pass voltage > Vcc, VIN = 5V, RLOAD \geq 1M Ω , no CLOAD).

SOME APPLICATIONS FOR HOTSWITCH PRODUCTS

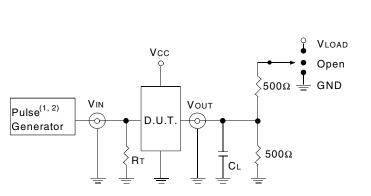




TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$VCC^{(1)}= 3.3V \pm 0.3V$	$VCC^{(2)} = 2.5V \pm 0.2V$	Unit
Vload	6	2 x Vcc	V
Vih	3	Vcc	V
VT	1.5	Vcc/2	V
Vlz	300	150	mV
Vhz	300	150	mV
CL	50	30	pF



Test Circuits for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

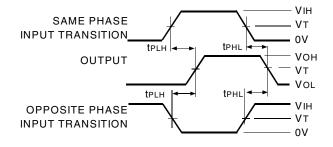
RT = Termination resistance: should be equal to Zout of the Pulse Generator.

NOTES:

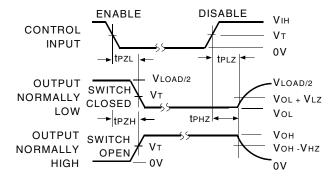
- 1. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tr \leq 2.5ns; tr \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2ns; tR \leq 2ns.

SWITCHPOSITION

Test	Switch
tplz/tpzl	Vload
tphz/tpzh	GND
tPD	Open



Propagation Delay



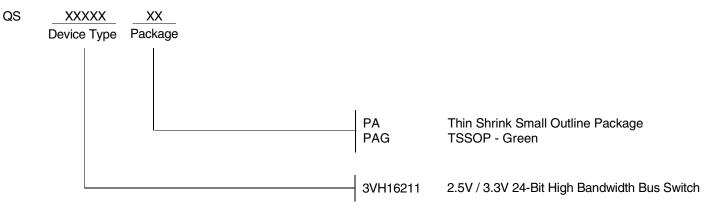
NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

INDUSTRIALTEMPERATURERANGE

ORDERING INFORMATION





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